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## Silicon solar cells textured using gold of induced etching

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As is known, a layer with a dielectric coating remains the standard of a photoelectric converter and many research groups are studying various alternative methods to achieve an antireflection effect in silicon for photovoltaic and other optoelectronic applications [1]. Some of these methods include electrochemical etching [2], sol-gel deposition [3], magnetron sputtering of metal oxide films [4], and anisotropic etching [5].

Ready-made structures with a p-n junction were used as the initial substrate, the specific resistivity of the  $n^+$  layer was 0.008-0.01 Ohm·cm and the total plate thickness was 300  $\mu$ m. Then, the front side of the sample is chemically activated in a solution of 0.4 mM, HAuCl<sub>4</sub> for 3-5 s, after which it is thoroughly washed in deionized water.

The output parameters of solar cells were determined from the characteristics. In particular, open circuit voltage  $U_{oc}=610$  mV, short-circuit current  $I_{sc}=32$  mA / cm2, duty cycle  $\xi=0.77$ , light emission power  $P_{max}=100$  mWt /cm², efficiency is  $\sim15.03\%$ .

## References

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